

### Features

- ✧ Plastic material used carriers Underwriters Laboratory Classification 94V-0
- ✧ Metal silicon junction, majority carrier conduction
- ✧ Low power loss, high efficiency
- ✧ High current capability, low forward voltage drop
- ✧ High surge capability
- ✧ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- ✧ Guard-ring for overvoltage protection
- ✧ High temperature soldering guaranteed: 260°C/10 seconds, 0.25"(6.35mm) from case
- ✧ Green compound with suffix "G" on packing code & prefix "G" on datecode



### Mechanical Data

- ✧ Cases: JEDEC TO-220AB molded plastic body
- ✧ Terminals: Pure tin plated, lead free, solderable per MIL-STD-750, Method 2026
- ✧ Polarity: As marked
- ✧ Mounting position: Any
- ✧ Mounting torque: 5 in. - lbs, max
- ✧ Weight: 1.88 grams

### Ordering Information(example)

Part No.	Package	Packing	Packing code	Packing code (Green)
MBR1035CT	TO-220AB	50 / TUBE	C0	C0G

### Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.

Parameter	Symbol	MBR 1035 CT	MBR 1045 CT	MBR 1050 CT	MBR 1060 CT	MBR 1090 CT	MBR 10100 CT	MBR 10150 CT	MBR 10200 CT	Units
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	35	45	50	60	90	100	150	200	V
Maximum RMS Voltage	$V_{RMS}$	24	31	35	42	63	70	105	140	V
Maximum DC Blocking Voltage	$V_{DC}$	35	45	50	60	90	100	150	200	V
Maximum Average Forward Rectified Current	$I_{F(AV)}$	10								A
Peak Repetitive Forward Current (Rated VR, Square Wave, 20KHz)	$I_{FRM}$	10								A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	$I_{FSM}$	120								A
Peak Repetitive Reverse Surge Current (Note 1)	$I_{RRM}$	1.0	0.5							A
Maximum Instantaneous Forward Voltage at (Note 2) IF=5A, TA=25°C IF=5A, TA=125°C IF=10A, TA=25°C IF=10A, TA=125°C	$V_F$	0.70 0.57 0.80 0.67	0.80 0.65 0.90 0.75	0.85 0.75 0.95 0.85	0.88 0.78 0.98 0.88					V
Maximum Instantaneous Reverse Current @ TA=25 °C at Rated DC Blocking Voltage @ TA=125 °C	$I_R$	0.1								mA
		15	10	2	5					mA
Voltage Rate of Change (Rated VR)	dV/dt	10,000								V/us
Maximum Typical Thermal Resistance	$R_{\theta JC}$	1.5								°C/W
Operating Junction Temperature Range	$T_J$	- 65 to + 150								°C
Storage Temperature Range	$T_{STG}$	- 65 to + 175								°C

Note 1: 2.0uS Pulse Width, f=1.0KHz

Note 2: Pulse Test : 300uS Pulse Width, 1% Duty Cycle

RATINGS AND CHARACTERISTIC CURVES (MBR1035CT THRU MBR10200CT)

FIG. 1- FORWARD CURRENT DERATING CURVE

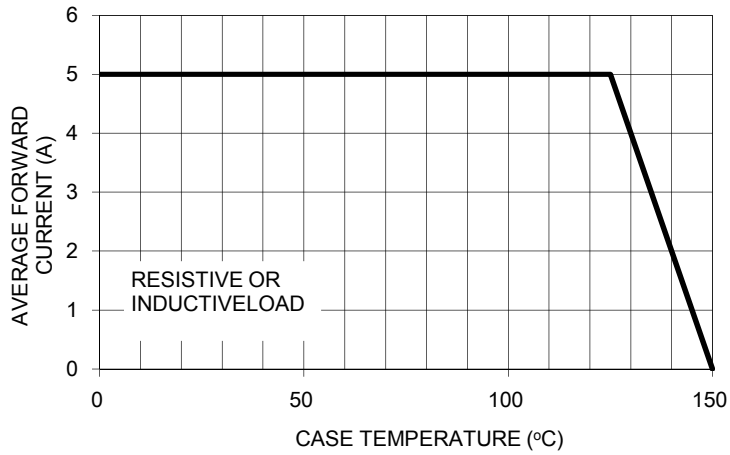


FIG. 2- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

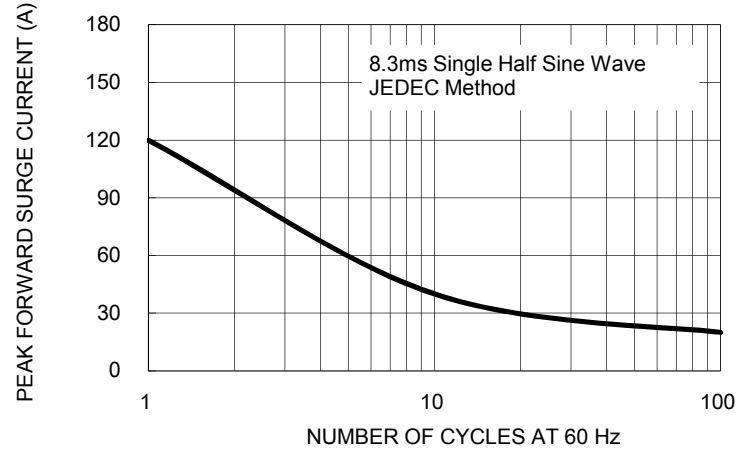


FIG. 3- TYPICAL FORWARD CHARACTERISTICS

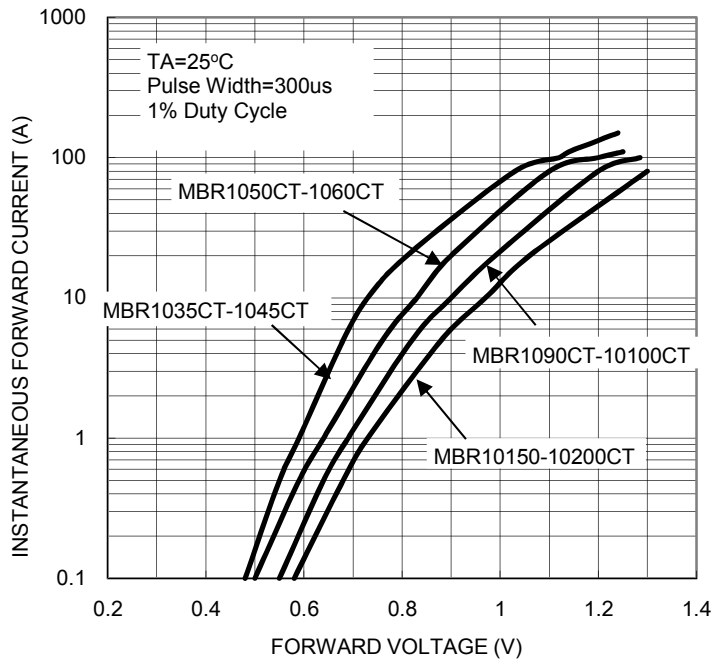


FIG. 4- TYPICAL REVERSE CHARACTERISTICS

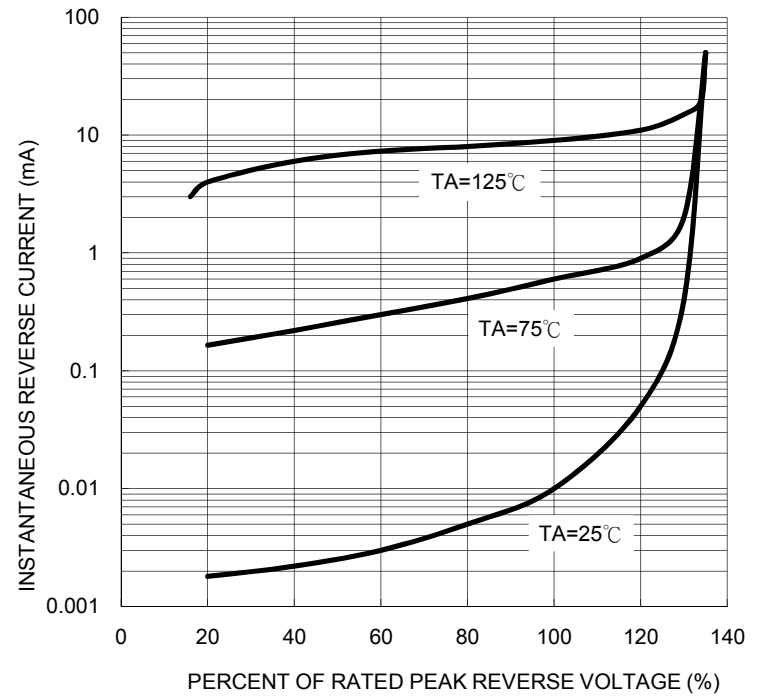


FIG. 5- TYPICAL JUNCTION CAPACITANCE

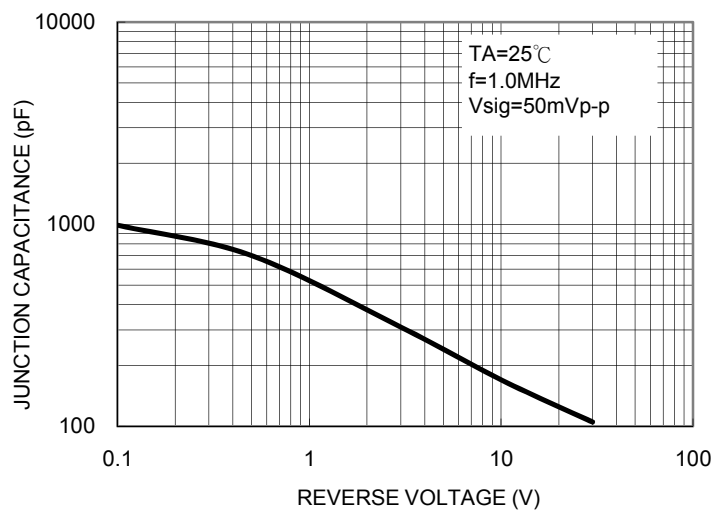
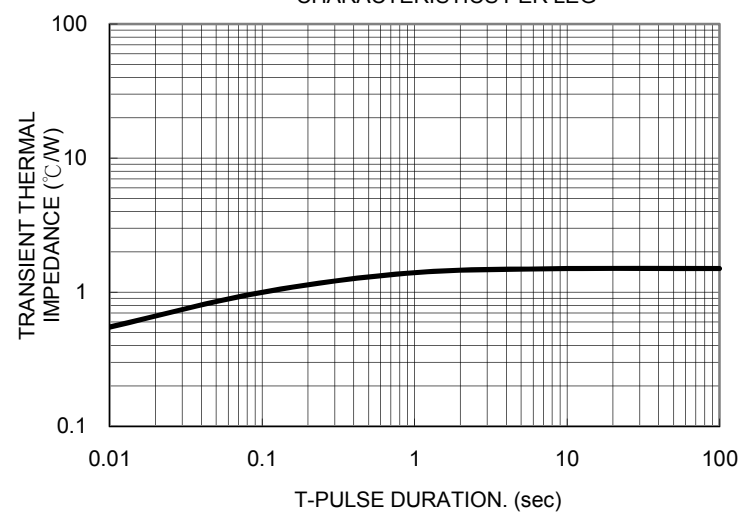


FIG. 6- TYPICAL TRANSIENT THERMAL CHARACTERISTICS PER LEG

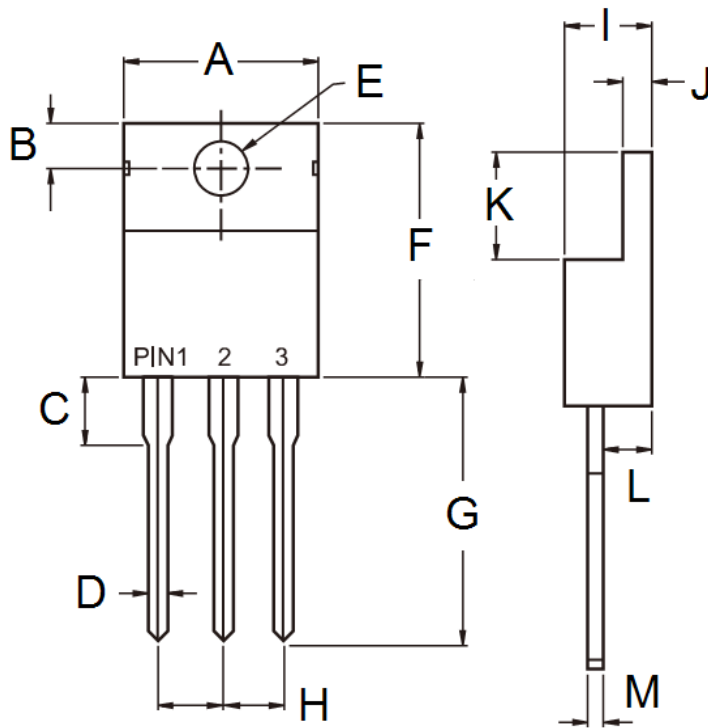


### Ordering information

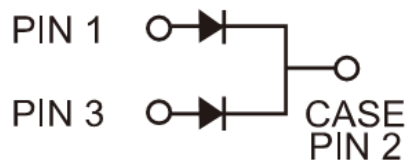
Part No.	Package	BULK Packing	Packing code	Packing code (Green)
MBR10xxCT	TO-220AB	50 / TUBE	C0	C0G

Note: "xx" is Device Code from "35" thru "200".

### Dimensions



DIM.	Unit(mm)		Unit(inch)	
	Min	Max	Min	Max
A	-	10.50	-	0.413
B	2.62	3.44	0.103	0.135
C	2.80	4.20	0.110	0.165
D	0.68	0.94	0.027	0.037
E	3.54	4.00	0.139	0.157
F	14.60	16.00	0.575	0.630
G	13.19	14.79	0.519	0.582
H	2.41	2.67	0.095	0.105
I	4.42	4.76	0.174	0.187
J	1.14	1.40	0.045	0.055
K	5.84	6.86	0.230	0.270
L	2.20	2.80	0.087	0.110
M	0.35	0.64	0.014	0.025



### Marking Diagram



P/N = Specific Device Code  
 G = Green Compound  
 YWW = Date Code

# Mouser Electronics

Authorized Distributor

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